Single SPST Analog Switch

The NLAS4501 is an analog switch manufactured in sub-micron silicon-gate CMOS technology. It achieves very low R_{ON} while maintaining extremely low power dissipation. The device is a bilateral switch suitable for switching either analog or digital signals, which may vary from zero to full supply voltage.

The NLAS4501 is pin-for-pin compatible with the MAX4501. The NLAS4501 can be used as a direct replacement for the MAX4501 in all 2.0 V to 5.5 V applications where a R_{ON} performance improvement is required.

The Enable pin is compatible with standard CMOS outputs when supply voltage is nominal 5.0 Volts. It is also over-voltage tolerant, making it a very useful logic level translator.

- Guaranteed R_{ON} of 32 Ω at 5.5 V
- Low Power Dissipation: $I_{CC} = 2 \mu A$
- Provides Voltage translation for many different voltage levels
 3.3 to 5.0 V, Enable pin may go as high as +5.5 Volts
 1.8 to 3.3 V
 1.8 to 2.5 V
- Improved version of MAX4501 (at any voltage between 2 and 5.5 Volts)
- Chip Complexity: FETs 11
- Pb-Free Packages are Available

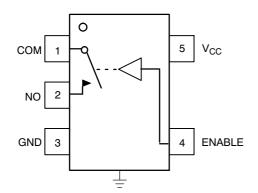


Figure 1. Pinout (Top View)



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MARKING DIAGRAMS





SC70-5/SC-88A/SOT-353 DF SUFFIX CASE 419A





SOT23-5/TSOP-5/SC59-5 DT SUFFIX CASE 483

d = Date Code

PIN ASSIGNMENT							
1	СОМ						
2	NO						
3	GND						
4	ENABLE						
5	V _{CC}						

FUNCTION TABLE

State of Analog Switch
Off
On

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

MAXIMUM RATINGS

Symbol	Pa	Value	Unit	
V _{CC}	Positive DC Supply Voltage	-0.5 to +7.0	V	
V _{IN}	Digital Input Voltage (Enable)		-0.5 to +7.0	V
V _{IS}	Analog Output Voltage (V_{NO} or V_{COM})		-0.5 to V _{CC} +0.5	V
l _{IK}	DC Current, Into or Out of Any Pin		±20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for	260	°C	
TJ	Junction Temperature under Bias		+ 150	°C
θ_{JA}	Thermal Resistance	SC70-5/SC-88A (Note 1) TSOP-5	350 230	°C/W
P _D	Power Dissipation in Still Air at 85°C	SC70-5/SC-88A TSOP-5	150 200	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 30% - 35%	UL-94-VO (0.125 in)	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 100 N/A	V
I _{Latch-Up}	Latch-Up Performance Above V _{CC} a	nd Below GND at 85°C (Note 5)	±300	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

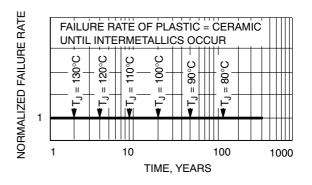
5. Tested to EIA/JESD78.

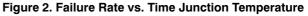
RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	2.0	5.5	V	
V _{IN}	Digital Input Voltage (Enable)	GND	5.5	V	
V _{IO}	Static or Dynamic Voltage Across an Off Switch	GND	V _{CC}	V	
V _{IS}	Analog Input Voltage (NO, COM)		GND	V _{CC}	V
T _A	Operating Temperature Range, All Package Types		-55	+125	°C
t _r , t _f	Input Rise or Fall Time, (Enable Input)	$V_{cc} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{cc} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0





DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

				–40°C			
Symbol	Parameter	Condition	V _{CC}	Min	Тур	Max	Unit
V _{IH}	Minimum High-Level Input Voltage, Enable Inputs		2.0 3.0 4.5 5.5	1.5 2.1 3.15 3.85	- - - -	- - - -	V
V _{IL}	Maximum Low-Level Input Voltage, Enable Inputs		2.0 3.0 4.5 5.5		- - - -	0.5 0.9 1.35 1.65	V
I _{IN}	Maximum Input Leakage Current, En- able Inputs	V _{IN} = 5.5 V or GND	0 V to 5.5 V	-	<u>+</u> 0.1	<u>+</u> 1.0	μA
I _{CC}	Maximum Quiescent Supply Current (per package)	Enable and VIS = VCC or GND	5.5	-	-	1.0	μA

DC ELECTRICAL CHARACTERISTICS – Analog Section

				–40°C	to +85°C		
Symbol	Parameter	Condition	V _{CC}	Min	Тур	Max	Unit
R _{ON}	Maximum ON Resistance (Figures 8 - 12)	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IH} \\ V_{IS} &= V_{CC} \text{ to GND} \\ I_{IS} I &= \le 10.0 \text{mA} \end{split}$	3.0 4.5 5.5	- - -	45 30 25	50 35 25	Ω
R _{FLAT(ON)}	ON Resistance Flatness	$V_{IN} = V_{IH}$ $I_{IS}I = \leq 10.0 \text{mA}$ $V_{IS} = 1V, 2V, 3.5V$	4.5	-	4.0	4.0	Ω
I _{NO(OFF)}	Off Leakage Current, Pin 2 (Figure 3)	$V_{IN} = V_{IL}$ $V_{NO} = 1.0 \text{ V}, V_{COM} = 4.5 \text{ V}$ or $V_{COM} = 1.0 \text{ V} \text{ and } V_{NO} 4.5 \text{ V}$	5.5	-	1.0	100	nA
I _{COM(OFF)}	Off Leakage Current, Pin 1 (Figure 3)	V _{IN} = V _{IL} V _{NO} = 4.5 V or 1.0 V V _{COM} = 1.0 V or 4.5 V	5.5	-	1.0	100	nA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

				Guaranteed Max Limit									
			v _{cc}	-5	5 to 25	5°C		<85°C	;		<125°0	2	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Мах	Min	Тур	Max	Min	Тур	Max	Unit
t _{ON}	Turn-On Time	R_L = 300 Ω , C_L = 35 pF (Figures 4, 5, and 13)	2.0 3.0 4.5 5.5		7.0 5.0 4.5 4.5	14 10 9 9			16 12 11 11			16 12 11 11	ns
t _{OFF}	Turn-Off Time	R_L = 300 Ω,C_L = 35 pF (Figures 4, 5, and 13)	2.0 3.0 4.5 5.5		11.0 7.0 5.0 5.0	22 14 10 10			24 16 12 12			24 16 12 12	ns

		Typical @ 25, V _{CC} = 5.0 V	
C _{IN}	Maximum Input Capacitance, Select Input	8	pF
C _{NO or} C _{NC}	Analog I/O (switch off)	10	
C _{COM} (OFF)	Common I/O (switch off)	10	
C _{COM} (ON)	Feedthrough (switch on)	20	

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			v _{cc}	Limit	
Symbol	Parameter	Condition	v	25°C	Unit
BW	Maximum On-Channel -3dB Bandwidth or Minimum Frequency Response	$V_{IS} = 0 \text{ dBm}$ V_{IS} centered between V_{CC} and GND (Figures 6 and 14)	3.0 4.5 5.5	190 200 220	MHz
V _{ONL}	Maximum Feedthrough On Loss	$V_{IS} = 0 \text{ dBm } @ 10 \text{ kHz}$ V_{IS} centered between V_{CC} and GND (Figure 6)	3.0 4.5 5.5	-2 -2 -2	dB
V _{ISO}	Off-Channel Isolation	f = 100 kHz; V_{IS} = 1 V RMS V _{IS} centered between V _{CC} and GND (Figures 6 and 15)	3.0 4.5 5.5	-93	dB
Q	Charge Injection Enable Input to Common I/O		3.0 5.5	1.5 3.0	рС
THD	Total Harmonic Distortion THD + Noise	$\label{eq:FIS} \begin{array}{l} F_{IS} = 20 \; \text{Hz to 1 MHz, R}_L = \text{Rgen} = 600 \; \Omega, \; C_L = 50 \; \text{pF} \\ V_{IS} = 3.0 \; V_{PP} \; \text{sine wave} \\ V_{IS} = 5.0 \; V_{PP} \; \text{sine wave} \\ \text{(Figure 17)} \end{array}$	3.3 5.5	0.3 0.15	%

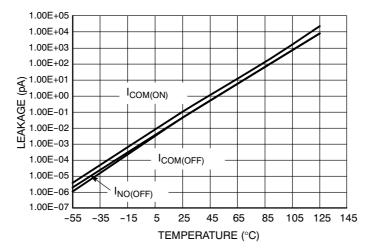


Figure 3. Switch Leakage vs. Temperature

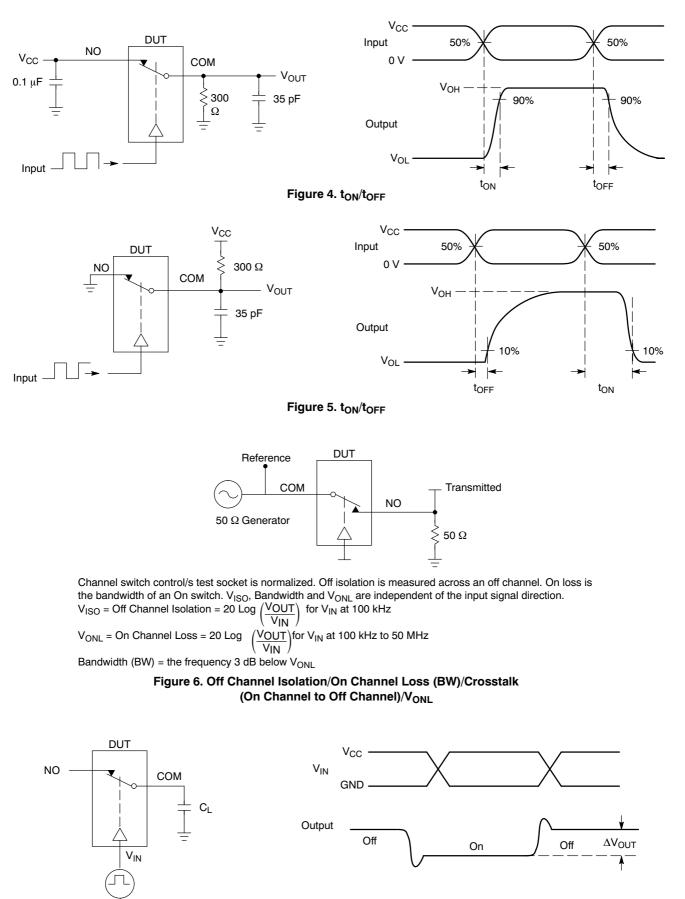
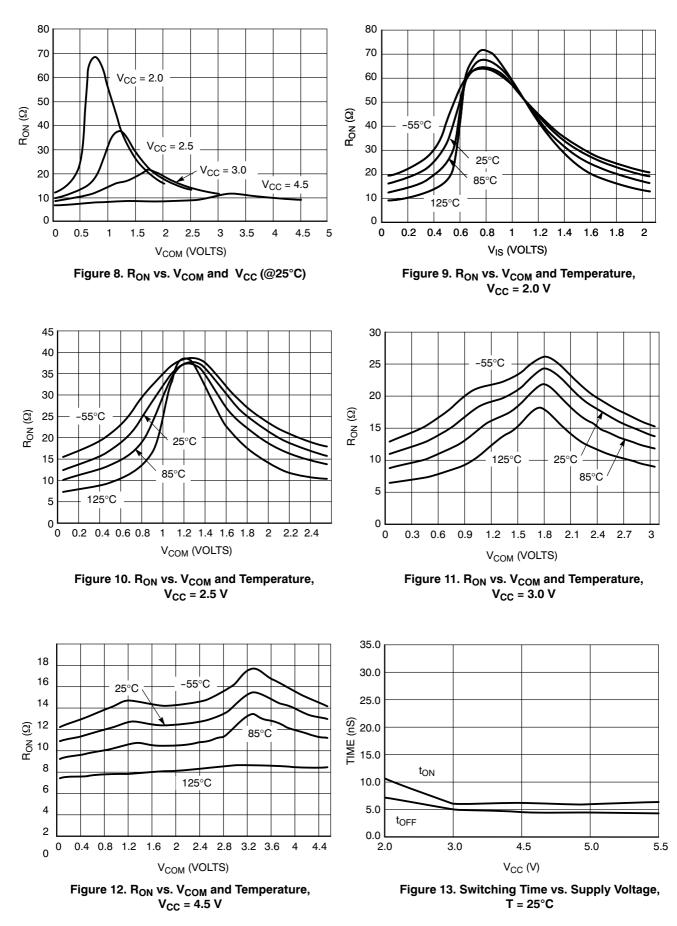
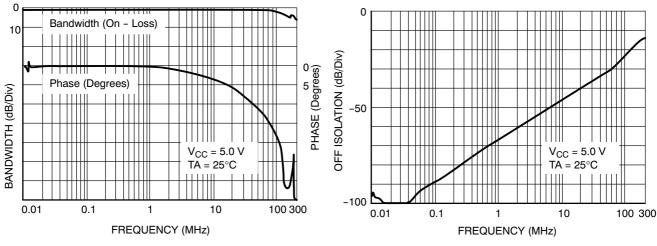


Figure 7. Charge Injection: (Q)







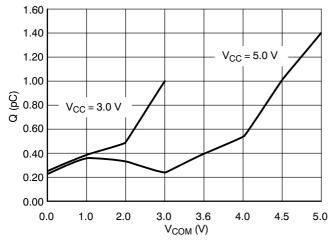


Figure 16. Charge Injection vs. V_{COM}

Figure 15. Off Channel Isolation

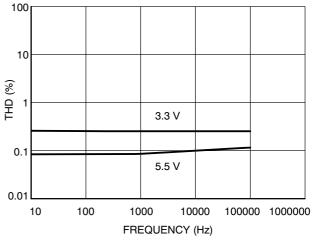


Figure 17. THD vs. Frequency

DEVICE ORDERING INFORMATION

		Devie	e Nomenclat				
Device Order Number	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Shipping [†]
NLAS4501DFT2	NL	AS	4501	DF	T2	SC-88A	178 mm (7) 3000 / Tape & Reel
NLAS4501DFT2G	NL	AS	4501	DF	T2	SC-88A (Pb-Free)	178 mm (7) 3000 / Tape & Reel
NLAS4501DTT1	NL	AS	4501	DT	T1	SOT-23/TSOP-5	178 mm (7 inch) 3000 / Tape & Reel
NLAS4501DTT1G	NL	AS	4501	DT	T1	SOT-23/TSOP-5 (Pb-Free)	178 mm (7 inch) 3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSEM



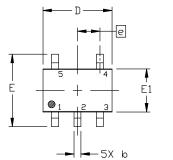
SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

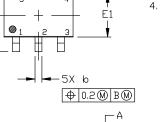
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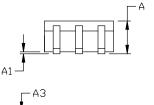
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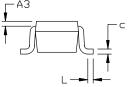
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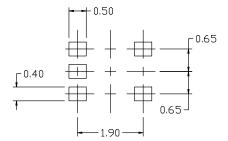
DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS					
MIU	MIN.	NDM.	MAX.			
A	0.80	0.95	1.10			
A1			0.10			
A3		0.20 REF	-			
b	0.10	0.20	0.30			
С	0.10		0.25			
D	D 1.80 2.00		5'50			
E	2.00	2.10	5'50			
E1	1.15	1.25	1.35			
e	0.65 BSC					
L	0.10	0.15	0.30			

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

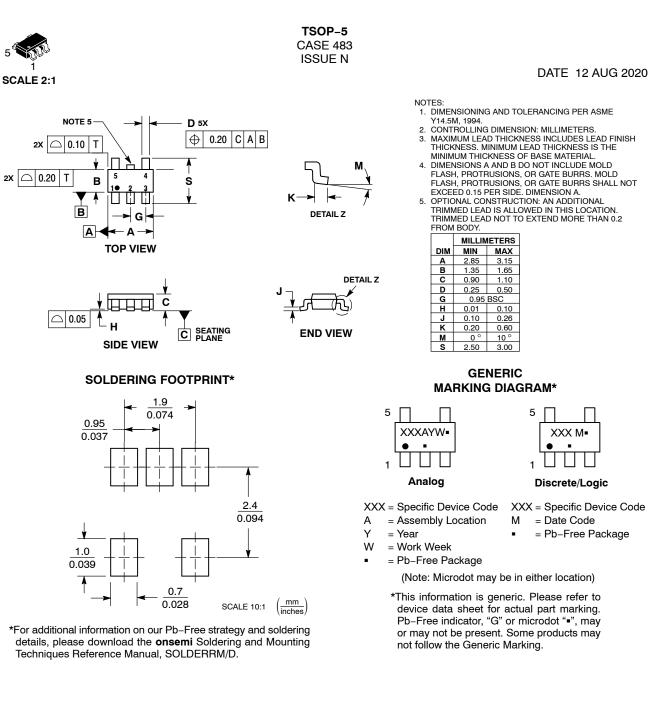
Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED (
DESCRIPTION:	SC-88A (SC-70-5/SOT-353)				PAGE 1 OF 1

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